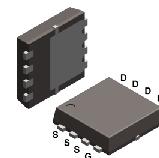


CMS52N04V8-HF

**N-Channel
RoHS Device
Halogen Free**



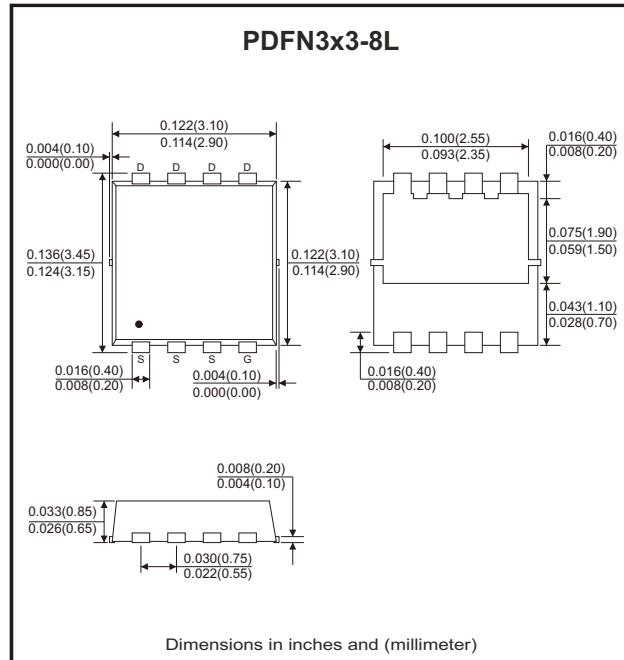
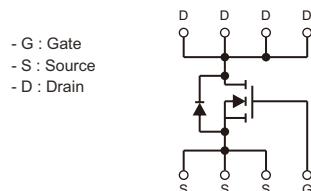
Features

- Low thermal resistance.
- Advanced high cell density trench technology.

Mechanical data

- Case: PDFN3x3-8L, molded plastic.
- Molding compound: UL flammability classification rating 94V-0.
- Terminals: Matte tin plated leads, solderability per MIL-STD-202, method 208.

Circuit Diagram



Maximum Ratings (at $T_C=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Value	Unit
Drain-source voltage	V_{DSS}	40	V
Gate-source voltage	V_{GSS}	± 20	V
Continuous drain current ($V_{GS}=10\text{V}$, $T_c=25^\circ\text{C}$) (Note 1)	I_D	52	A
Continuous drain current ($V_{GS}=10\text{V}$, $T_c=100^\circ\text{C}$) (Note 1)	I_D	33	
Pulsed drain current ($V_{GS}=10\text{V}$, $T_c=25^\circ\text{C}$) (Note 1,2,3)	I_{DM}	144	A
Single pulse avalanche energy ($V_{DD} = 40\text{V}$, $L = 1\text{mH}$)	E_{AS}	91	mJ
Power dissipation ($T_c=25^\circ\text{C}$)	P_D	20.8	W
Thermal resistance junction to case (Note 1)	$R_{\theta JC}$	6	$^\circ\text{C}/\text{W}$
Thermal resistance junction to air (Note 1)	$R_{\theta JA}$	62.5	$^\circ\text{C}/\text{W}$
Operating junction temperature range	T_J	-55 to +150	$^\circ\text{C}$
Storage temperature range	T_{STG}	-55 to +150	$^\circ\text{C}$

Electrical Characteristics (at TA=25°C unless otherwise noted)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Static Characteristics						
Drain-source breakdown voltage	V _{DSS}	V _{GS} = 0V, I _D = 250μA	40			V
Zero gate voltage drain current	I _{DSS}	V _{DS} = 32V, V _{GS} = 0V			1	μA
Gate-body leakage current	I _{GSS}	V _{GS} = ±20V, V _{DS} = 0V			±100	nA
On Characteristics						
Static drain-source on-resistance (Note 2)	R _{D(on)}	V _{GS} = 10V, I _D = 15A			4.6	mΩ
	R _{D(on)}	V _{GS} = 4.5V, I _D = 10A			7	mΩ
Gate threshold voltage	V _{GS(th)}	V _{DS} = V _{GS} , I _D = 250μA	1		2	V
Dynamic Characteristics (Note 4)						
Input capacitance	C _{iss}	V _{GS} = 0V, V _{DS} = 20V, f = 1MHz		916		pF
Output capacitance	C _{oss}			348		
Reverse transfer capacitance	C _{rss}			48		
Switching Characteristics (Note 4)						
Turn-on delay time	t _{d(on)}	V _{DD} = 20V, V _{GS} = 10V R _G = 3.9Ω, R _L = 1.33Ω, I _D = 15A		5.7		ns
Turn-on rise time	t _r			24		
Turn-off delay time	t _{d(off)}			24		
Turn-off fall time	t _f			18		
Total gate charge	Q _g	V _{DD} = 20V, V _{GS} = 10V, I _D = 15A		21		nC
Gate to source charge	Q _{gs}			3.7		
Gate to drain (miller) charge	Q _{gd}			4.7		
Source-Drain Diode Characteristics						
Diode forward voltage (Note 2)	V _{SD}	I _{SD} = 15A, V _{GS} = 0V			1.3	V
Drain continuous forward current	I _s	T _c = 25°C			52	A
Reverse recovery time	t _{rr}	I _{SD} = 15A, di/dt = 100A/μs		22		ns
Reverse recovery charge	Q _{rr}			7.2		nC

- Notes:
1. Surface mounted on 1 in² pad area, t ≤ 10 sec.
 2. The data tested by pulsed, pulse width ≤ 300μs, duty cycle ≤ 2%.
 3. Limited by bonding wire.
 4. Guaranteed by design, not subject to production testing.

Rating and Characteristic Curves (CMS52N04V8-HF)

Fig.1 - Typical Output Characteristics

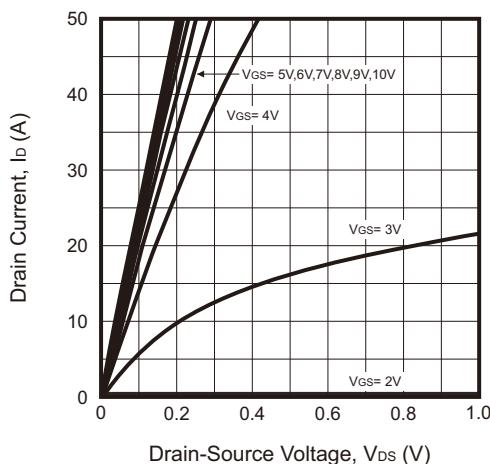


Fig.2 - On-Resistance vs. Drain Current and Gate Voltage

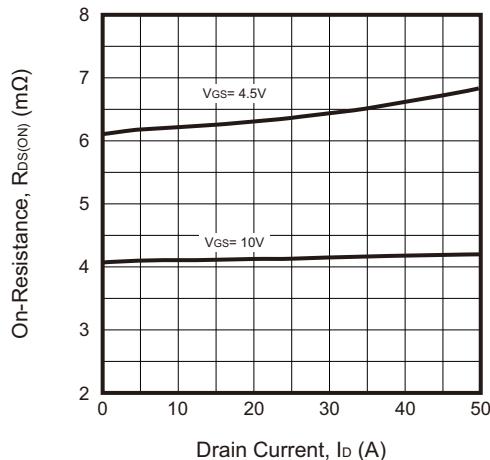


Fig.3 - On-Resistance vs. Gate-Source Voltage

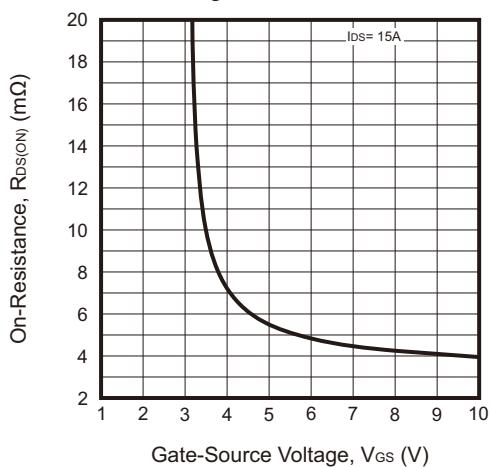


Fig.4 - Body-Diode Characteristics

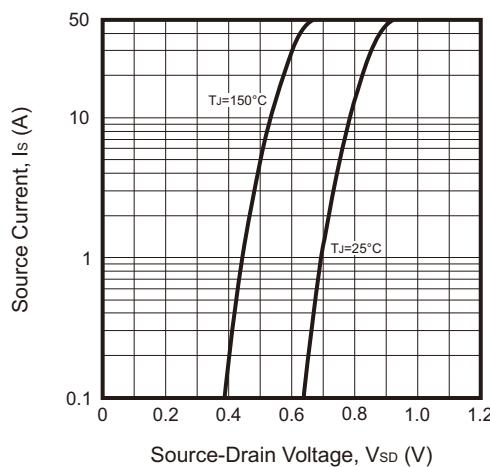


Fig.5 - On-Resistance vs. Junction Temperature

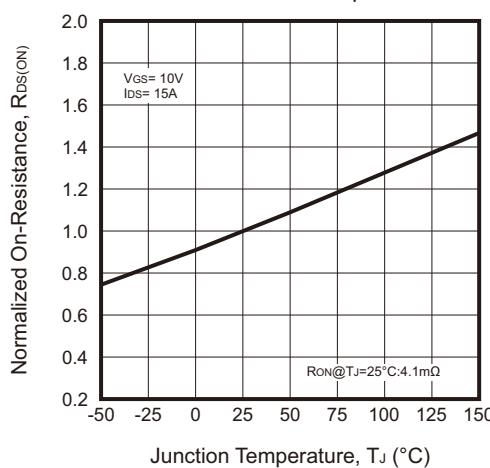
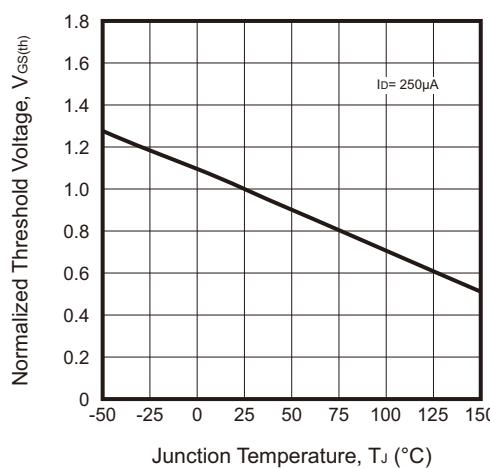


Fig.6 - $V_{GS(th)}$ vs. Junction Temperature



Rating and Characteristic Curves (CMS52N04V8-HF)

Fig.7 - Capacitance Characteristics

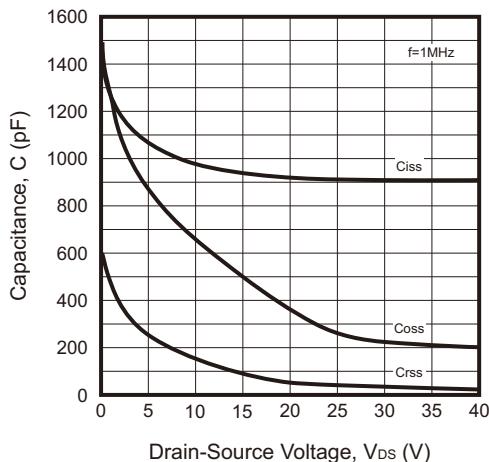


Fig.8 - Maximum Safe Operating Area

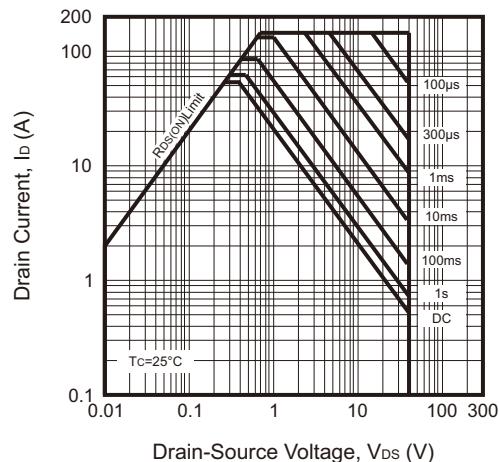


Fig.9 - Current Capability

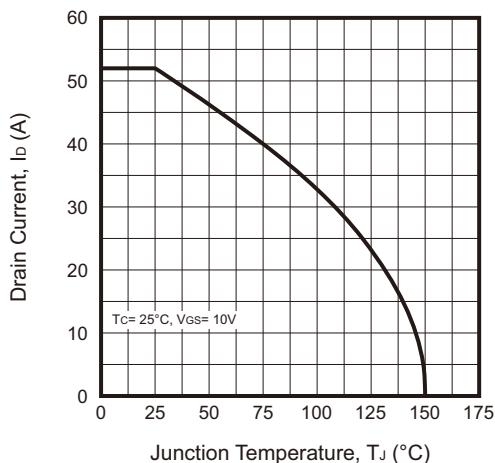


Fig.10 - Power Capability

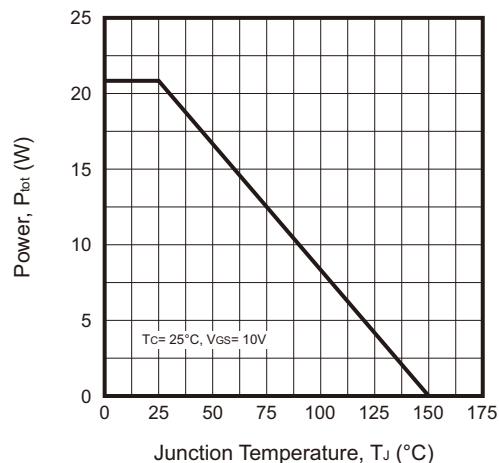
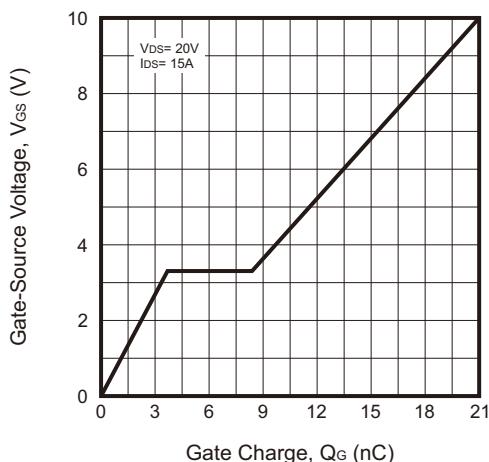
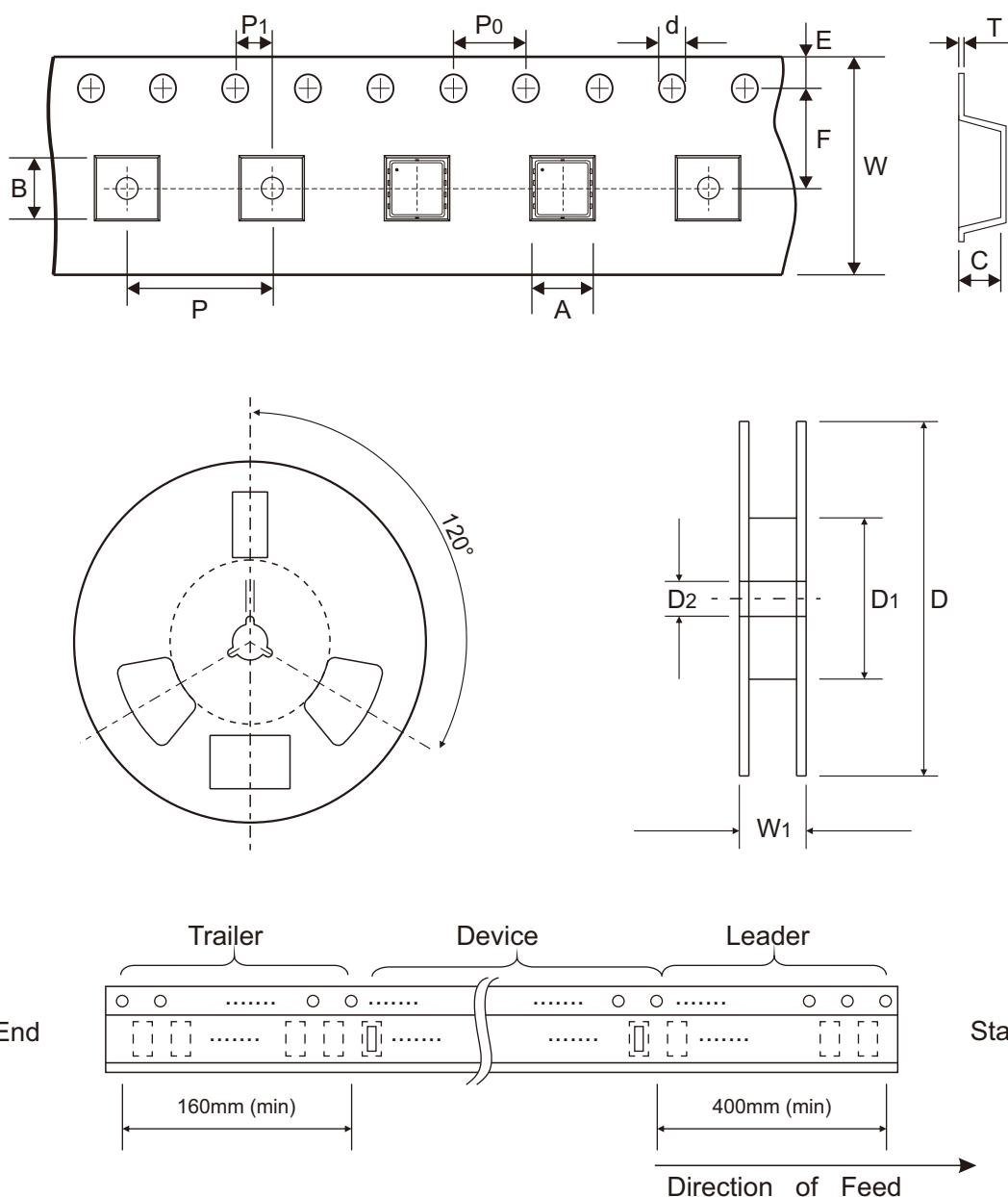


Fig.11 - Gate-Charge Characteristics



Reel Taping Specification

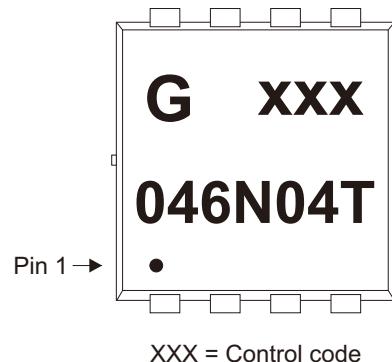


PDFN3x3 -8L	SYMBOL	A	B	C	d	D	D ₁	D ₂
	(mm)	3.60 ± 0.10	3.60 ± 0.10	1.20 ± 0.10	$1.50 + 0.10$ $- 0.00$	330 ± 1.00	100 ± 1.00	13.00 ± 0.20
	(inch)	0.142 ± 0.004	0.142 ± 0.004	0.047 ± 0.004	$0.059 + 0.004$ $- 0.000$	12.992 ± 0.039	3.937 ± 0.039	0.512 ± 0.008

PDFN3x3 -8L	SYMBOL	E	F	P	P ₀	P ₁	T	W	W ₁
	(mm)	1.75 ± 0.10	5.50 ± 0.05	8.00 ± 0.10	4.00 ± 0.10	2.00 ± 0.05	0.25 ± 0.02	$12.00 + 0.30$ $- 0.10$	17.80 ± 0.30
	(inch)	0.069 ± 0.004	0.217 ± 0.002	0.315 ± 0.004	0.157 ± 0.004	0.079 ± 0.002	0.010 ± 0.001	$0.472 + 0.012$ $- 0.004$	0.701 ± 0.012

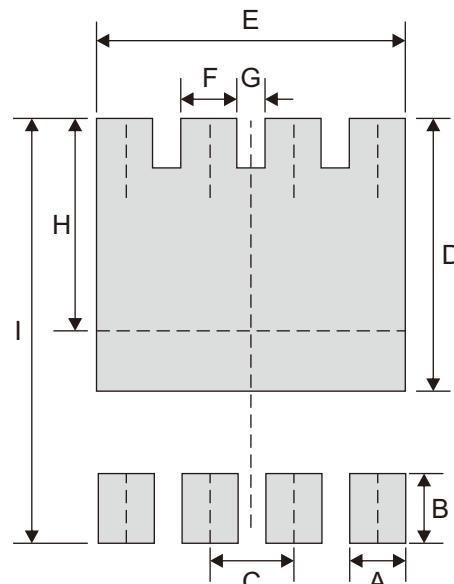
Marking Code

Part Number	Marking Code
CMS52N04V8-HF	046N04T



Suggested P.C.B. PAD Layout

SIZE	PDFN3x3-8L	
	(mm)	(inch)
A	0.42	0.017
B	0.70	0.028
C	0.65	0.026
D	2.25	0.089
E	2.37	0.093
F	0.42	0.017
G	0.23	0.009
H	1.85	0.073
I	3.70	0.146



Standard Packaging

Case Type	REEL PACK	
	REEL (pcs)	Reel Size (inch)
PDFN3x3-8L	5,000	13